8-BIT SINGLE-CHIP MICROCOMPUTER

GENERAL DESCRIPTION

The TMP8049PI-6, from here on referred to as the TMP8049, is a single chip microcomputer fabricated in N-channel Silicon Gate MOS technology which provides internal 8-bit parallel architecture.

The following basic architectural functions of a computer have been included in a single chip; an 8-bit CPU, 128 x 8 RAM data memory, 2K x 8 ROM program memory, 27 I/O lines and an 8-bit timer/event counter.

The TMP 8049 is particularly efficient as a controller. It has extensive bit handing capability as well as facilities for both binary and arithmetic.

The TMP8039PI is the equivalent of a TMP8049 without ROM program memory on chip. By using this device with external EPROM or RAM, software debugging becomes easy.

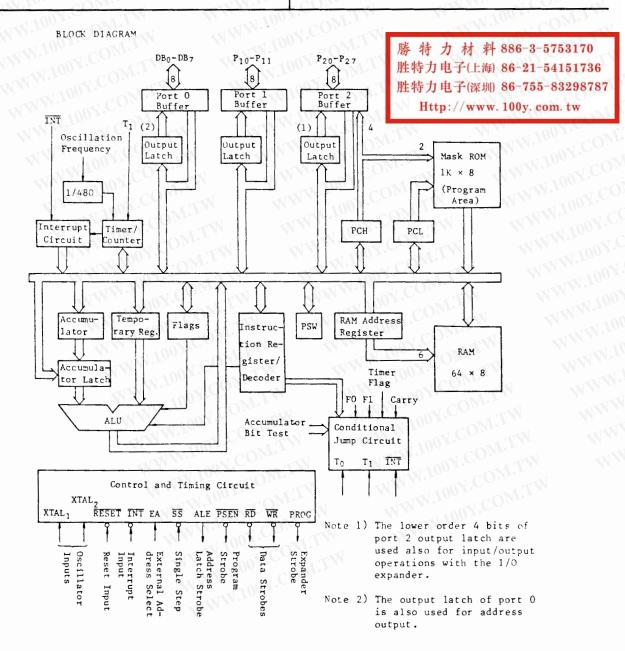
### FEATURES

- . 2.5 µS Instruction Cycle
- . All instruction 1 or 2 cycles
- . Over 90 instructions; 70% single byte . Interval Timer/Event Counter
- . Easy expandable memory and I/O
- . 2K x 8 masked ROM

- . 128 x 8 RAM
- . 27 I/O lines
- . Single level interrupt
- . Single 5V supply
  - -40°C to +85°C Operation

PIN CONNECTIONS (Top View)





TMP8049PI-6, TMP8039PI-6

PIN NAMES AND PIN DESCRIPTION

VSS (Power Supply)
Circuit GND potential

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VDD (Power Supply)

+5V during operation Low power standby pin for TMP 8049 RAM

VCC (Main Power Supply) +5V during operation

PROG(Output)

Output strobe for the TMP 8243P I/O expander

P10-P17 (Input/Output) Port 1 8-bit quasi -bidirectional port (Internal Pullup=50kΩ).

P20-P27 (Input/Output) Port 2

8-bit quasi-bidirectional port (Internal Pullup=50k $\Omega$ ). P 20-P 23 Contain the four high order program counter bits during an external program memory fetch and serve as a 4-bit I/O expander bus for the TMP 8243P.

DBO-DB7 (Input/Output, 3 State)

True bidirectional port which can be written or read synchronously using the  $\overline{\text{RD}}$ ,  $\overline{\text{WR}}$  strobes. The port can also be statically latched. Contains the 8 low order program counter bits during an external program memory fetch, and receives the addressed instruction under the control of  $\overline{\text{PSEN}}$ . Also contains the address and data during an external RAM data store instruction, under control of ALE,  $\overline{\text{RD}}$ , and  $\overline{\text{WR}}$ .

- TO (Input/Output)
  Input pin testable using the conditional transfer instructions JTO and
  JNTO. TO can be designated as a clock output using ENTO CLK instruction.
- T1 (Input) Input pin testable using the JTl and JNTl instruction. Can be designated the event counter input using the timer/STRT CNT instruction.
- INT (Input)

  External interrupt input. Initiates an interrupt if interrupt is enabled. Interrupt is disabled after a reset. Also testable with conditional jump instruction. (Active Low)
- RD (Output)
  Output strobe activated during a Bus read. Can be used to enable data
  onto the Bus from an external device. Used as a Read Strobe to External
  Data Memory (Active Low).
- WR (Output)
  Output strobe during a Bus write (Active Low) Used as a Write Strobe to External Data Memory.

TMP8049PI-6, TMP8039PI-6

RESET (Input)

Active Low signal which is used to initialize the Processor. Also used during Power down.

ALE (Output)

Address Latch Enable. This signal occurs once during each cycle and is useful as a clock output. The negative edge of ALE strobes address into external data and program memory.

PSEN (Output)

Program Store Enable. This output occurs only during a fetch to external program memory (Active Low).

SS (Input)

Single step input can be used in conjunction with ALE to "single step" processor through each instruction when  $\overline{SS}$  is low the CPU is placed into a wait state after it has completed the instruction being excuted.

EA (Input)

External Access input which forces all program memory fetches to reference external memory. Useful for emulation and debug and essential for testing and program verification. (Active High).

XTAL 1 (Input)

One side of crystal input for internal oscillator. Also input for external source.

XTAL 2 (Input)

Other side of crystal input.

FUNCTIONAL DESCRIPTION

1. System Configuration

The following system functions of the TMP 8049 are described in detail.

(1) Program Memory

(6) Stack (Stack Pointer)

(2) Data Memory

(7) Flag 0, Flag 1

(3) I/O Port

(8) Program Status Word (PSW)

(4) Timer/Counter

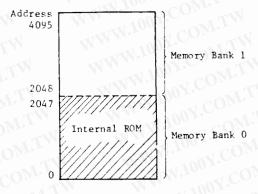
- (9) Reset
- (5) Interrupt Control Circuit
- (10) Oscillator Circuit

(1) Program Memory \

The maximum memory that can be directly addressed by the TMP 8049 is 4096 bytes. The first 2048 bytes from location 0 through 2047 can be internal resident mask ROM. The rest of the 2048 bytes of addressable memory are external to the chip. The TMP 8039 has no internal resident memory; all memory must be external.

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There are three locations in Program Memory of special importance.



Program Memory Area

. Location 0

Activating the Reset line of the processor causes the first instruction to be fetched from Location 0.

. Location 3

Activating the interrupt line of the processor (if interrupt enabled) causes a jump to subroutine defined by address held in Location 3.

. Location 7

A timer/counter interrupt resulting from a timer/counter overflow (if enabled) causes a jump to a subroutine defined by address held in Location 7.

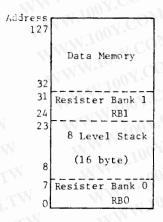
Program address 0-2047 and 2048-4095 are called memory banks 0 and 1 respectively switching of memory banks is achieved by changing the most significant bit of the program counter (PC) during execution of an unconditional jump instruction or call instruction executed after using SEL MBO or SEL MB1.

Reset operation automatically selects Bank 0.

#### (2) Data Memory

- . Resident Data Memory (volatile RAM) is organized as 128 words by 8-bits
- . The first 8 locations (0 -7) of the memory array are designated as working registers and are directly addressable by several instructions. By executing a Register Bank switch instruction (SEL RB1) locations 24 31 are designated as the working registers in place of 0 7.

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Internal Data Memory Area

- . RAM locations 8 23 serve a dual role in that they contain the program counter stack which is a stack 2 bytes wide by 8 levels deep. These locations store returning addresses from subroutines. If the level of subroutine nesting is less than the permitted 8, you free up 2 bytes of RAM for general use for every level of nesting not utilized.
- . ALL 128 locations are indirectly addressable through either of two RAM Pointer Registers which reside at RO and RI of the Register array.
- . The TMP8049 architecture allows extension of the Data Memory to 256 words.

#### (3) Input/Output Ports

- . The TMP8049 has 27 I/O lines which can be used for either input or output. These I/O lines are grouped into 3 ports each having 8 bidirectional lines and 3 "test" inputs which can alter program sequences when tested by conditional jump instructions.
- Ports 1 and 2 are each 8-bits wide and have identical characteristics. Data written to these ports is statically latched and remains unchanged until rewritten. As input ports these lines are non-latching, i.e., inputs must be present until read by an input instruction.
- . All lines of Ports 1 and 2 are called quasi-bidirectional because of a special output circuit structure (illustrated in Figure 1). Each line is continously pulled to a +5V level through a high impedance resistive device ( $50k\Omega$ ) which is sufficient to provide the source current for a TTL high level yet can be pulled low by a standard TTL gate thus allowing the same pin to be used for both input and output. In order to speed up the "0" to "l" transition a low impedance device ( $5k\Omega$ ) is switched in momentarily whenever a "l" is written to line. When a "0" is written to line a low impedance device overcomes the pullup and provides TTL current sinking capability.

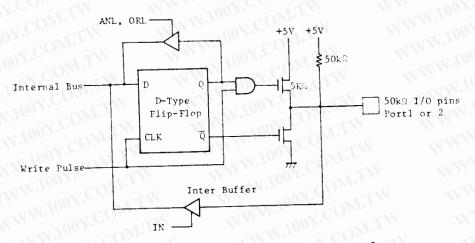


Fig.1 Input/Output Circuit of Port 1, Port 2

- . Reset initializes all lines to a high impedance "1" state.
- When external data memory area is not addressed during excution of an internal program, Port 0 (DBO DB7) becomes a true bidirectional port (bus) with associated input and output strobes. If bidirectional feature not needed Bus can serve as either a statically latched output port or a non-latched input port. However, I/O lines of this port cannot be intermixed.
- . As a static port data is written and latched using the OUTL instruction and inputted using the INS instruction these two commands generate pulses on the corresponding  $\overline{RD}$  and  $\overline{WR}$  strobe lines.
- . As a bidirectional port the  $\overline{MOVX}$  instructions are used to read and write the port which generate the  $\overline{RD}$  and  $\overline{WR}$  strobes.
- . When not being written or read, the Bus lines are in a high impedance state.

### (4) Timer/Event Counter

. The 8-bit binary up counter can use either of the following frequency inputs

(1) Internal clock (1/480 of OSC frequency)
...... Timer mode

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(2) External input clock form Tl terminal
(minimum cycle time 3 x ALE cycle)
...... Event Counter mode

The counter is presettable and readable with two MOV instructions which transfer the content of the accumulator to the counter and vice versa. The counter content is not affected by a Reset and is initialized solely by the MOVT, A instruction. The counter is stopped by a Reset or STOP TCNT instruction and remains stopped until started by START T instruction or as an event counter by a START CNT. Once started the counter will increment to its maximum count (FF) and overflow to Zero continuing its count until stopped by a STOP TCNT instruction or RESET.

The increment from maximum count to Zero (overflow) results in the setting of an overflow flag and the generation of an interrupt request. When interrupt acknowledged a subroutine call to Location 7 will be initiated. Location 7 should store the starting address of the timer or counter service routine. The state of the overflow flag is testable with the conditional JUMP (JTF). The flag is reset by excuting a JTF or by RESET. Figure 2 illustrates the concept of the timer circuit.

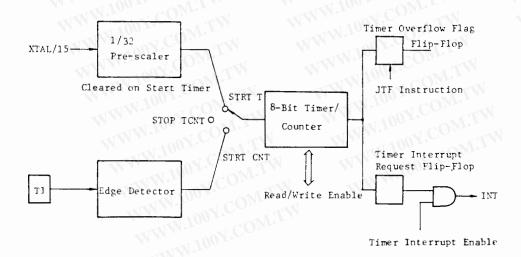
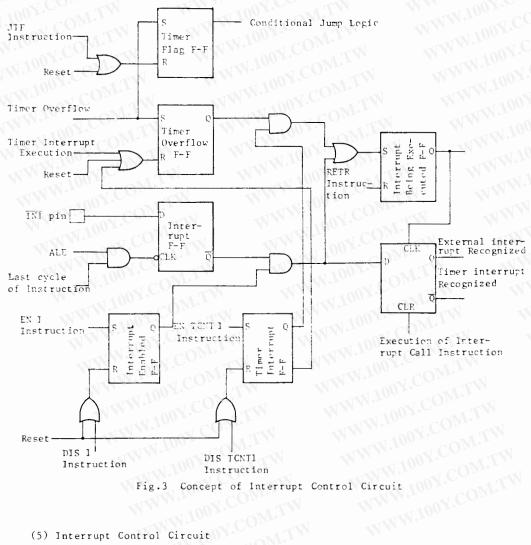


Fig.2 Concept of Timer Circuit

# INTEGRATED CIRCUIT TECHNICAL DATA



### (5) Interrupt Control Circuit

- . There are two distinct types of Interrupts in the TMP 8049.
  - (1) External Interrupt from the INT terminal
  - (2) Timer Interrupt caused by timer overflow

### TMP8049PI-6, TMP8039PI-6

# TOSHIBA INTEGRATED CIRCUIT

The interrupt system is single level in that once an interrupt is detected all further interrupt requests are ignored until execution of an RETR (which should occur at the end of an interrupt service routine) reenables the interrupt input logic.

- An interrupt sequence is initiated by applying a low level "0" to the INT pin. INT is level triggered and active low which allows "Wire Oring" of several interrupt sources. The interrupt level is sampled every machine cycle during ALE and when detected causes a "jump to subroutine" at Location 3. As in any call to subroutine, the Program Counter and Program Status Word are saved in the stack.
- . When an overflow occurs in the internal timer/event counter an interrupt request is generated which is reserviced as outlined in previous paragraph except that a jump to Location 7 is used instead of 3. If INT and times overflow occur simultaneously then external request INT takes precedence.
- . If an extra external interrupt is needed in addition to  $\overline{ ext{INT}}$  this can be achieved by enabling the counter interrupt, loading FFH in the counter (one less than the terminal count), and enabling the event counter mode. A "l" to "0" transition on Tl will cause an interrupt vector to Location 7.
- . The interrupt service routine pointed to be addresses in Location 3 or 7 must reside in memory between 0 and 2047, i.e., Bank 0.

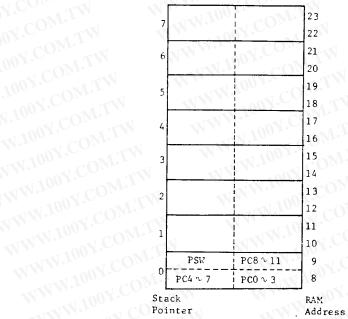
Figure 3 illustrates the concept of the interrupt control circuit.

### (6) Stack (stack Pointer)

- . An interrupt or Call to subroutine causes the contents of the program counter to be stored in one of the 8 register pairs of the Program Counter Stack. The pair to be used is determined by a 3-bit stack pointer which is part of the Program Status Words (PSW explained in section (8)). Data RAM locations, 8 through 23 are available as stack registers and are used to store the program counter and 4-bits of PSW as shown in the figure.
- . The stack pointer when initialized points to RAM location 8 and 9. The first subroutine jump or interrupt results in the program counter contents being transferred to Locations 8 and 9. Then the stack pointer is incremented by one to point to Locations 10 and 11. Eight levels of subroutine are obviously possible.
- At the end of a subroutine signalled by a RET or RETR causes the stack pointer to be decremented by one and the contents of the resulting pair to be transferred to the Program Counter.

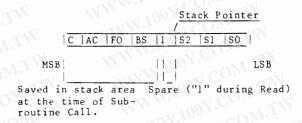
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# INTEGRATED CIRCUIT TOSHIBA TECHNICAL DATA



- (7) Flag 0, Flag 1, F3. F1)
  - . The TMP8049 has two flags FO and Fl which are used for conditional jump. These flags can be set, reset and tested with the conditional jump instruction JFO.
  - . FO is a part of the program status word (PSW) and is saved in the stack area when a subroutine is called.
- (8) Program Status Word (PSW)
  - . An 8-bit status word which can be loaded to and from the accumlator exists called the Program Status Word (PSW). The PSW is read by a MOV A, PSW and written to by a MOV PSW, A. The information available in the PSW is shown in the diagram below. WWW.1007.CON

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Bits 0 - 2 : Stack Pointer Bits(SO, S1, S2)
Bit 3 : Not used ("1" level when read.)
Bit 4 : Working Register Bank Switch Bit
(BS)

0 = Bank 0 1 = Bank 1

Bit 5 : Flag 0 (F0)

Bit 6 : Auxiliary Carry (AC) carry bit generated by an ADD

instruction and used by the decimal adjust instruction

DA, A (AC)

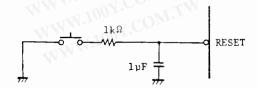
Bit 7 : Carry (C) flag which indicates that the previous

operation has resulted in the accumulator.

(C)

### (9) Reset

. The reset input provides a means for initialization of the processor. This Schmitt trigger input has an internal pullup registor which in combination with an external lµF capacitor provides an internal reset pulse sufficient length to guarantee that all internal logic is initialized.



### TMP8049PI-8, TMP8039PI-8

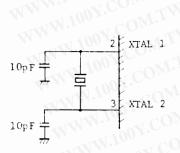
If the pulse is generated externally the reset pin must be held at ground ( $\leq 0.5$ V) for at least 50mS after the power supply is within tolerance.

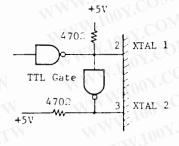
. Reset performs the following functions within the chip:

- (i) Sets PC to Zero.
- (ii) Sets Stack Pointer to Zero.
- (iii) Selects Register Bank 0.
- (iv) Selects Memory Bank 0.
- (v) Sets BUS (DBO DB 7) to high impedance state. (Except when EA = 5V)
  - (vi) Sets Ports 1 and 2 to input mode.
  - (vii) Disables interrupts (timer and external).
    - (viii) Stops Timer.
- (ix) Clears Timer Flag.
  - (x) Clears FO and Fl.
  - (xi) Disables clock output from TO.

### (10) Oscillator Circuit

. TMP8049 can be operated by the external clock input in addition to crystal oscillator as shown below.





#### 2. Basic Operation and Timing

The following basic operations and timing are explained

- (1) Instruction Cycle
- (2) External Memory Access Timing
- (3) Interface with I/O Expander TMP8243P
- (4) Internal Program Verify (Read) Timing
- (5) Single Step Operation Timing
- (6) Low Power Stand-by Mode

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### (1) Instruction Cycle

- . The instructions of TMP8049 are executed in one or two machine cycles, and one machine cycle contents of five states.
  - . Fig. 4 illustrates its relationship with the clock input to CPU.
  - . 62 clock shown in Fig.4 is derived to outside by ENTO CLK instruction.
  - ALE can be also used as the clock to indicate the machine cycle as well as giving the external address latch timing.

### (2) External Memory Access Timing

#### (i) Program Memory Access

- . TMP8049 programs are excuted in the following three modes.
  - (1) Execution of internal program only.
    - (2) Execution of both external and internal programs.
    - (3) Execution of external program only.

The external program memory is accessed (instructions are fetched) automatically when the internal ROM address is exceeded in mode (2) and from initial start address 0 in mode (3).

- . In the external program memory access operation, the following will occur
  - . The contents of the 12-bit program counter will be output on BUS(DBO DB7) and the lower 4-bits of Port 2.
  - . Address Latch Enable (ALE) will indicate the time at which address is valid. The trailing edge of ALE is used to latch the address externally.
  - Program Store Enable (PSEN) indicates that an external instruction fetch is in progress and serves to enable the external memory device.
  - . BUS (DBO DB7) reverts to Input mode and the processor accepts its 8-bit contents as an Instruction Word.
- . Figure 5 illustrates the timing.

#### (ii) Access of External Data Memory

- . In the extended data memory access operation during READ/WRITE cycle the following occurs
- . The contents of RO R1 is output onto BUS (DBO DB7).
- . ALE indicates address is valid. The trailing edge of ALE is used to latch the address externally.
- . A read  $\overline{RD}$  or write  $\overline{WR}$  pulse on the corresponding output pins indicates the type of data memory access in progress. Output data valid at trailing edge of  $\overline{WR}$  and input data must be valid at trailing edge of  $\overline{RD}$ .
- . Data (8-bits) is transferred over BUS.

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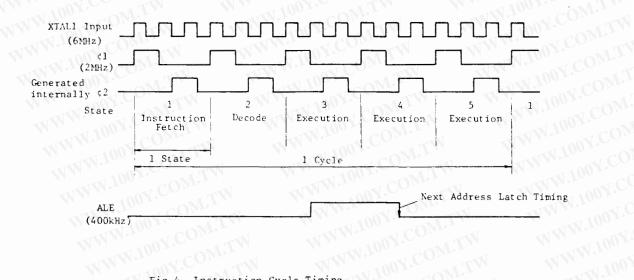


Fig.4 Instruction Cycle Timing WWW.100Y.COM.TW WWW.100Y.COM

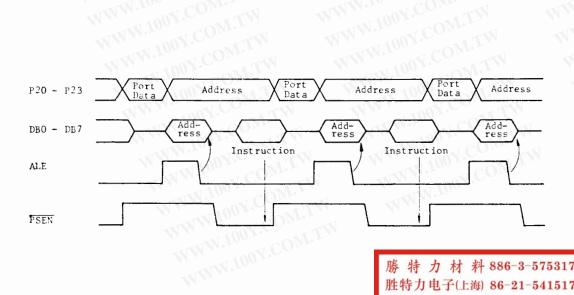
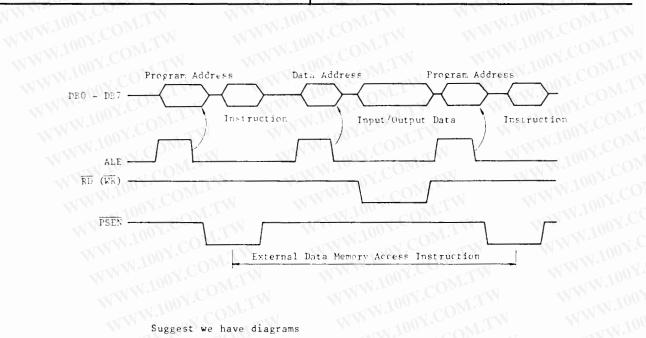


Fig. 5 Timing of External Program Memory Access



Suggest we have diagrams

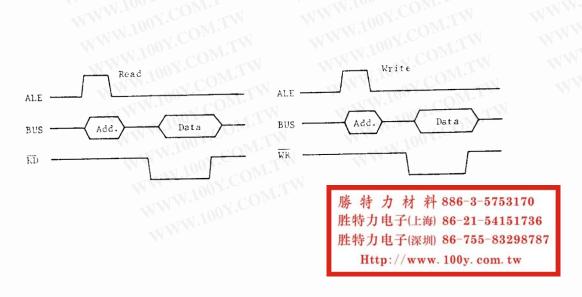


Fig. 6 Timing of Accessing External Data Memory

- Figure 6 illustrates the timing of accessing the external data memory during execution of external program.
- (3) Interface with I/O Expander (TMP8243P)
  - The TMP8049 I/O can be easily expanded using the TMP8243 I/O Expander. This device uses only the lower half 4-bits of Port 2 for communication with the TMP8049. The TMP8243 contains four 4-bit I/O ports which serve as extensions of one chip I/O and are addressed as Ports (4-7). All communication takes place over the lower half of port 2 (P2O P23) with timing provided by an output pulse on the PROG pin. Each transfer consists of two 4-bit nibbles the first containing the "OP Code" and port address and the second containing the actual 4-bits of data.

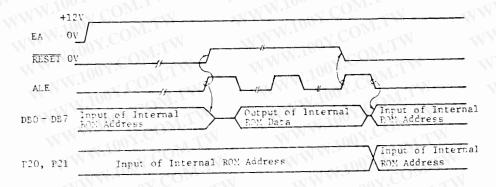


Fig.7 Timing of Reading Internal Program Memory

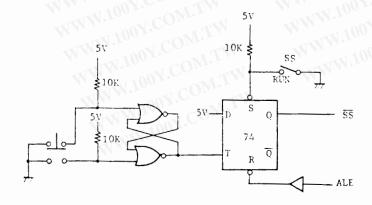


Fig.8 (a) Single Step Circuit

Reading of Internal Program Memory

- . The process<u>or</u> is placed in the READ mode by applying +12V to the EA pin and 0V to the RESET pin. The address of the location to be read is then applied to BUS and the low order 2-bits of Port 2. The address is latched by a 0 to 1 transition on RESET and the high level causes the contents of program memory location addressed to appear on the eight lines of BUS.
- . Figure 7 illustrates the timing diagram for this operation.
- (5) Single Step Operation.
- . A single step feature useful for debug can be implemented by utilizing a circuit shown in Figure 8 (a) combined with the SS pin and ALE pin.
- . A D-type flip flop with set and reset is used to generate SS. In the run mode SS is held high by keeping the flip flop set. To enter single step, set is removed allowing ALE to bring SS low via reset input. The next instruction is started by clocking a "l" into the FF which will not appear on SS unless ALE is high removing reset. In response to SS going high the processor begins an instruction fetch which brings ALE low resetting FF and causing the processor to again enter the stopped state.
- . The timing diagram in this case is as shown in Figure 8 (b). (EA = 5V).
- (6) Lower Power Stand-by Mode.
  - . The Lower TMP8049 has been organized to allow power to be removed from all but the volatile, 128 x 8 data RAM array. In power down mode the contents of data RAM can be maintained while drawing typically 10 15% of normal operating power requirements.
  - . VCC serves as the 5V supply for the bulk of the TMP8049 while the VDD supplies only the RAM array. In standby mode VCC is reduced to 0V but VDD is kept at 5V. Applying a low level to reset inhibits any access to the RAM by the processor and guarantees that RAM cannot be inadvertently altered as power is removed from VCC.

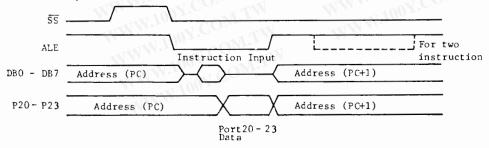


Fig.8(b) Single Step Operation Timing

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# INTEGRATED CIRCUIT TECHNICAL DATA

# TMP8049PI-6, TMP8039PI-6

Mnemonic	T:	Ins	tru	ctio	on (	Code	9		~ CU	Putas	Cualas	Flag
rinemonic	D7	D6	D5	D4	D3	D2	Dl	DO	Operation	Bytes	Cycles	CAC
ADD A,Rr	0	1	1	0	1	r	r	r	(A) < -(A) + (Rr) r = 0 - 7	1	1	0 0
ADD A,@Rr	0	1	1	0	0	0	0	r 	(A) < -(A) + ((Rr))   r = 0, 1	1	1	0 0 0
ADD A, #Data	0	0	0	0	0	0	1	1	(A)<-(A)+Data	2	2	0 0
TO 100 1			<b>d</b> 5						M. V. V. V. V. CO. V. V.	1		W.10
ADDC A,Rr	0	1	1	1	ĺ	r			(A) < -(A) + (Rr) + (C)  r = 0 - 7	1		0 0 100
ADDC A,@Rr	0	1	1.1	1	0	0	0		(A)<-(A)+((Rr))+  (C)	TI	1	
M. W.	IC.	72		W					r = 0, 1			Al Al
ADDC A, #Data	0	1 1		1	0				$(A) \langle -(A) + Data + (C)$	2	2	0 0
AVI A Direct OO			d5									NN I
ANL A, Rr	0	C		1	W		ĺ		(A) < -(A) and $(Rr)r = 0 - 7$			
ANL A,@Rr	0		0	1	0	0	0	r	(A) < -(A) and $((Rr))$		1	-1 -1
ANT A ADAM			1	1		0	 ! 1		r = 0, 1			
ANL A,#Data	0	-7	0  d5			- 1			(A) < -(A) and Data	2	2	
ORL A, Rr	0	U							(A)<-(A) or (Rr)		1	
OKL A, KI							N.	1	r = 0 - 7			
ORL A,@Rr	0	1	0	0	0	0	0	r	(A) < -(A) or $((Rr))r = 0, 1$	V.OO	1	
ORL A, #Data	10	1	0	0	0	0	1	d 1	(A)<-(A) or Data	2	2	o(-   -   .
M. M.	d7	d6	145	d4	d3					10 7	LAN	1
XRL A, Rr	1	1	0	1	1	r	r	r	(A) < -(A) EOR (Rr) r = 0 - 7	1001.0	1	-
XRL A,@Rr	1	1	0	oi	0	0	0	r	(A) < -(A) EOR((Rr)) r = 0, 1	Tody	l	711
XRL A, #Data	1	1					1		(A)<-(A) EOR Data	2	1 2	-100
	d7	d6	<b>d</b> 5	d4	d3	d2	dl			11.100	Lan	A.F.
INC A	30.70		0						$(A) \langle -(A) + 1$	1	1 1	-1-1
DEC A	0		1						(A)<-(A)-1	10	1 10	1241
CLR A	0								(A)<-0	1	1	
CPL A	0			1 0				1 1 2 1	(A)<-NOT (A)	1.1	1	0-315-1
DA A	0	1	0		0	1			Decimal Adjust Accumulator		1	0 - 1
SWAP A	0	1	0	0	0		1	1	(A4-7)->(A0-3) <-	1		-
		4							TW .			

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Mnemonic	Instruction Code	ag   AC
RL A	1   1   1   0   0   1   1   1   (An+1)<-(An)   1   1   -	TOO.
100		Jul 3
RLC A	1 1 1 1 0 1 1 1 (An+1)<-(An) 1 1 1 1 -	1,400
1.100Y.CC		N 10
N. C	(A0)<-(C)	
RR A	$0 \mid 1 \mid 1 \mid 1 \mid 0 \mid 1 \mid 1 \mid 1 \mid (An) \leftarrow (An+1) \qquad   \qquad 1 \qquad   \qquad 1 \qquad   \qquad -$	141.7
1007		
RRC A	0 1 1 1 0 0 1 1 1 1 (An) (-(An+1) 1 1 1 -	121

V	4	Ins	tru	ctio	n (	Code	2			( ) Mr.		F1	ag !
Mnemonic	D7	D6	D5	D4	D3	D2	Dl	D0	Operation	Bytes	Cycles	C	ag AC
IN A,Pp									(A)<-(Pp)		2	-	-
	Lo								P = 1, 2		i TW		ĺ
OUTL Pp,A	1 0	0	1.1	1	1	0	P	P	(Pp)<-(A)		2	- ;	- ]
	1	50		!					P = 1, 2		TV TV		
ANL Pp, *Data	1 1	0	0	1	1	0	P	P	(Pp) <- (Pp) and Data	1 2	2	(I - }	-
	d7	id6	d5	d4	d3	d2	dl	d0	P = 1, 2	7		1	1
ORL Pp,#Data	1 1	0	0	0	1	0	P	P	(Pp)<-(Pp)or Data	20	2	Œ;	- !
	d7	d6	d5	d4!	d3	d2	d1	d0	P = 1, 2	00 5.			
INS A, BUS	1 0	0	0	0 !	1	0	0	0	(A)<-(BUS)	-17	2	-	-
OUTL BUS, A	10	0	0	0	0	0	1	0	(BUS)<-(A)	1001	2	- !	-
ANL BUS,#Data	1	0	0	1	1	0	0	0	(BUS) <- (BUS) and	2	2	7	04:
	d7	d6	d5	d4!	d3	d2	d1	0.5	Data	100 ,		1	
ORL BUS,#Data	1	0	0	0	1	0	0	0	(BUS)<-(BUS) or	2	√ <b>2</b>	-1	
	1 d7	d6	d5	d4	d3	d2	dl	<b>d</b> 0	Data	$\times 10^{0}$		11.	
MOVD A,Pp	1 0	0	0	0	1	1	P	P	(A0-3)<-(Pp)	1	2	- 1	4
		Τ`	L	110		1			(A4-7)<-0	W.10	1	100	- 4
	1					K.			P = 4 - 7			1	
MOVD Pp,A	1 0	! 0	1	1	1	1	P	P	$(P_p) < -(A0-3)$		2	, - <u> </u>	-
	-	W		1					P = 4 - 7		!	1	i
ANLD Pp,A	1 1	0	0	1	1	1	P	P	(Pp)<-(Pp)and	1	2	- ]	-
	-	1				00	V.		(A0-3)	1	!	F	
	1					LUU			P = 4 - 7			1	
ORLD Pp,A	1	0	0	0	1	1	P	P	(Pp)<-(Pp)or(A0-3)	1	2	- 1	-
	+					$\mathcal{J}_{\mathcal{U}}$			P = 4 - 7	į	1	ĺ	

# INTEGRATED CIRCUIT TECHNICAL DATA

	7   D C   D C   D 2   D 2   D 1   D 0	Operation	Bytes	Cycles Flag
	7   D6   D5   D4   D3   D2   D1   D0   D   D   D   D   D   D   D   D	(Rr)<(Rr)+1	1	1
V.Co.		r = 0 - 7	ļ	IN 1 400
NC @Rr   C	0 0 0 1 0 0 0 0 1	((Rr)) < -((Rr))+1	1	1

Branch Instru	ictic	n					W				M		
Mnemonic	D7	D6						DO	Operation	Bytes	Cycles		ag
IMP Address									(PCO-7)<(a0-7)	2	2		-
								a0	(PC8-10)<(a8-10) (PC11) <dbf< td=""><td>TIN</td><td></td><td>N</td><td></td></dbf<>	TIN		N	
IMPD GA	1	0	1	0		0	1		(PCO-7)<((A))	T	2	- 3	17
JMPP @A	1		1						(Rr) <(Rr) - 1	2	1 2	_	_
DJNZ Rr,									if Rr not 0	2	2 1	_	
Address	a/	lab	las	a4	וכב	az	lar:		(PCO-7)<(a0-7)	DIM.	1.41	1	
			D = 1	- 1			, ,			1			
JC Address	001	1	1	1	0	1	1		(PC0-7) <(a0-7)	2	2	- ;	_
		1		- 4	3		- 1		if C = 1		TW		
	a/	ab	ao	au I	as	a2	aı		(PC) = (PC)+2   if C = 0	COM	4	1	
	1						١,					1	
JNC Address									(PCO-7)<-(a0-7)	2	1 Z	- !	_
	a/	ab	ab	a4			al		if C = 0			,	
	N.)	No.			M		:		(PC)<(PC)+2	127 CO	N. L.		
WW					_	K 11	1		if C = 1			N .	
JZ Address		1							(PCO-7)<(aO-7)	<1 <sup>2</sup> C)	D N 2	<b>(1)</b>	-
	l a/	ab	ab	a4	as	a2	al		if (A) = 0	101.	1.12		
	o V	1.1		-7	$^{\circ}C$	)ZA)			(PC)<(FC)+2	×1 (	OM		J
1			00	7					if (A) .NEQ.0	100%.		1	
JNZ Address									(PCO-7)<(a0-7)	2	COZ	-	κÑ
	a7	a6	a5	a4	a3	a2			if (A) .NEQ.0	1002		7.7	
			1.2		-T	HO	MA		(PC)<(PC)+2	1	4 COn		
				00	13.				if(A) = 0	100		1	1
JTO Address		0							(PCO-7)<(a0-7)	2	20	-	-
	a7	a6	a5	1 a 4	a3	a2	al		if TO = 1	10	1 3.	M	
				-	1	7	10		(PC)<(PC)+2	111.	ST.C	D. P.	ĺ
		M.		1	00	70			if TO = 0	- XXI 1	00		
JNTO Address						1			(PCO-7)<(a0-7)	2	2	\ <del>-</del>	-
	a7	a6	a5	a4	a3	a2	al		if TO = 0				
	1		TV				7		(PC) <(PC) + 2				
				1	11	100	7.0		lif TO = 1				
JTl Address	0	1	1 0	1	0	1	1	0	(PC0-7) <(a0-7)	2	2	-	-
	a7	a6	a5	a4	a3	a2	al	a0	if Tl = l	1			
	1	ļ	1	V	MA			1	(PC)<(PC)+2				
				1					if Tl = 0	,			
JNT1 Address	0	1	0	0	0	1	1	0	(PCO-7)<(a0-7)	2	2	-	-
	a7	a6	1 a 5	1a4	la3	a2	al	a0	if Tl = 0	1			
	1		1	1			1	1	(PC)<(PC)+2	1			
		1		1			1		lif T1 = 1	1	1		1

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Mnemoni	c		lnsı	truc	cti	on (	Code	2		Operation	Bytes	Cycles	Flag
7.	M	D7	D6	D5	D4	D3	D2	DI	DO	COM	ĺ	L	CAC
FO Addre	ss	1	0	l	1	0	1	1	0	(PCO-7)<(a0-7)	2	2	- (4)
		a7	a6	a5	a4	a3	a2	al	aO	if $FO = 1$	1		
	0	- 1		}		1				(PC)<(PC)+2		1 1 1	-110
	10	17.7	1		i				M.	if $F0 = 0$	1		
Fl Addre	ss	0	1	1	1	0	1	1	0	(PCO-7)<(a0-7)	2	2	-10-0
	0	a7	a6	a5	<b>a</b> 4	a3	<b>a</b> 2	al	aO	if $Fl = 1$	1-1	1	NN of
			T		ļ					(PC) < (PC) +2			
	. 1	OD	100						W	if F1 = 0	L		
TF Addre	SS			0			l	1		(PCO-7)<(a0-7)	2	2	-1 -1
		a7	a6	a5	a4	a3	a2	al		if $TF = 1$			
	DX:				M	1				(PC)<(PC)+2		1	AL I
	ار	. 0							<	if $TF = 0$		1	
NI Addre	ss	1 ]	0	0	0	0	1	1	0	(PCO-7)<(a0-7)	2	2	-1 -1
		a7	a6	a5	a4	a3	<b>a</b> 2	al	<b>a</b> 0	if INT = 0		t I	
	100	7.		-						(PC) < (PC) + 2		1	1 1
	1	<b>=</b> 7								if INT = 1	1		LAN
Bb Addre	ss	b2	ы	Ъ0	1	0	0	1	0	(PC0-7) <(a0-7)	2	2	-1 -1
	1	a7	a6	a5	a4	a3	a2	al	a0	if $Bb = 1$	D.	HVV I	1 4
		00							į .	(PC) < -(PC) + 2	LOM.	1	1 1
	M.		<j< td=""><td>ĊЧ</td><td>12.</td><td></td><td>N.</td><td></td><td>1</td><td>if <math>Bb = 0</math></td><td>CO</td><td>I Wal</td><td>ii</td></j<>	ĊЧ	12.		N.		1	if $Bb = 0$	CO	I Wal	ii
		101	7.						1	(b = 0 - 7)		į į	ii
CALL Addr	ess	a10	a9	a8	1	0	1	0	0	((SP))<	2	2	-1 -1
				a5			a2	al				17.	
	W	1	0.0	N.						(SP)<(SP)+1	N.Co	W	
		<b>XX</b> 1	100				1.)			(PC8-10) <(a8-10)	1	Mr.	
	V	11.			,C	V -				(PCO-7)<(a0-7)			N
		-137	11							(PC11) <dbf< td=""><td></td><td>OM</td><td></td></dbf<>		OM	
EΤ	W	1	0	0	0	0	0	4		(SP)<(SP)-1	1001	2 1	
			N.	Oa	ĺ		M	1.1		(PC)<((SP))		LOM.	181
ETR	N.	1	0	0	1	0	0	1		(SP)<(SP)-1		2	TW
	i		N	11				M		(PC)<((SP))	10.	CON	
	1	NV			ooi	V.4				(PSW4-7)<((SP))	1.100		

### Flag Manipulation Instruction

Mnemonic	Instruction Code Operation	Bytes	Cycles Flag
1	D7 D6 D5 D4 D3 D2 D1 D0	- TXX 1	CAC
CLR C	1 0 0 1 0 1 1 1 1 (c)< 0	1	1   0 -
CPL C	1 0 1 0 0 1 1 1 1 (C) < NOT (C)	1	1 0 -1
CLR FO	1 0 0 0 0 0 1 0 1 (F0)< 0	1 1	1   -  -
CPL FO	1  0  0  1  0  1  0  1 (F0) <not(f0)< td=""><td>1</td><td>1 1 -1 -1</td></not(f0)<>	1	1 1 -1 -1
CLR F1	1 0 1 0 0 1 0 1 (F1)< 0	1	1   -  -
CPL Fl	1 0 1 1 0 1 0 1 0 1 (F1) < NOT(F1)	! 1	1   -  -

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# INTEGRATED CIRCUIT TECHNICAL DATA

Mnemonic				ctic				44	Operation	Bytes	Cycles	
CON	-		_	D4	D3							CIAC
MOV A, Rr	1	1	1	1 1	1	r	r	r	(A)< (Rr)	[ ]	1	177.70
MOV A, @Rr	1	1	$\mathbb{N}_1$	1 1	0	0	0		r = 0 - 7   (A) < ((Rr))	1	1	12.00
A, eki	M	1	. «1	1					r = 0.1	koší		NN.
MOV A, #Data	0	0	1	0	0	0	l	1	(A) <data< td=""><td>2</td><td>2</td><td> 10</td></data<>	2	2	10
M.10	d71	d6	d5	144	<b>d</b> 3	d2	dl	dO	M. J. COM			
MOV Rr, A	1	0	1	0	1	r	r	r	(Rr)<(A)	1	1 1	-L-N.1
WW.	CA	74.		W				N	r = 0 - 7			MINIT
MOV@Rr,A	1)	0	1	0	0	0	0	r	((Rr))<-(A)	1 1	1	
			10.1		١,			V	r = 0, 1 (Rr) <data< td=""><td></td><td>1 0</td><td>AN Y</td></data<>		1 0	AN Y
MOV Rr,#Data	1		7.	1-1	1	r	r		$ \mathbf{r}  = 0 - 7$	2	2	
MOV@Rr,#Data									( (Rr)) <data< td=""><td>2</td><td>1 2</td><td>-1-1</td></data<>	2	1 2	-1-1
HOVERI, FDALA									r = 0, 1	DN -2	W 2	
MOV A.PSW									(A)< (PSW)		1 1	
MOV PSW, A				1		- 1	1		(PSW)<(A)	i i	i	1
XCH A, Rr	0			0			r		(A)>(Rr)	l î	1	
	400	M.			N 17			l	(4-W)		1711	
	To		, ,		1.				r = 0 - 7	F COD	T.	
XCH A, @Rr	0	0	-1	0	0	0	0	r	$ (A)\rangle((Rr))$	1	1	-! -!
TIN'	N.		√J	CU	17.		αŃ		<	KI CU		
XCHD A,@Rr	0	0	1	! 	0	0	0	-	r = 0, 1 (A0-3)> ((Rr0-3))	] 10		
ACRD A, ERI	U			L.C	0			N.	(AU-3)> ((KIU-3))			N
	-TV	1,31	)\( \)		40	M		-1	r = 0, 1	I -1 (	JOM.	
MOVX A,@Rr	1	0	0	0	0	0	0	r	(A)<((Rr))	1001	2	[ - ] - i
, i	-XX	N.	L.V.	1			7.		r = 0, 1	1	COA	N
MOVX @Rr,A	1	0	0	1	0	0	0	r	((Rr))<(A)	101	2	-   -
	σĪV			1	7	Ŋυ	100		r = 0, 1	1	Co	W
MOVP A, @A	1	0	1	0	0	0	1	1	(PCO-7)<(A)	110	2	()= -
101777 2 4 64	W		1 1				μ·	l .	(A)<((PC))	100	1	
MOVP3 A,@A	1			0	0	0			(PC0-7)<(A)  (PC8-11)<0011	110	2	1000
	V			i L- 1	00				(A)<((PC))	1 - 11	001	
		J-411		1		×1	T		(1.07)	MAN.	- CV.C	

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# INTEGRATED CIRCUIT **TOSHIBA** TECHNICAL DATA

Mnemonic	L	Ιn	st	ruc	tio	n C	ode	4	LV.CONP	В	vtes	Cycle	es	Flag
						D3			DO	i	,		_	CAC
MOV A,T	0	W	1	0	0	0	0	1 !	$0 \mid (A) <(T)$		1	1		-1.00
MOV T,A	1 0	1	1	1	0 :	0;	0 !	1	0   (T)<(A)		1	1		-1 -;
STRT T	! 0	1	1	0	1!	0	1	0	l Counting is   started in t  timer mode	he	1	1		N.30
STRT CNT	101		1	0	0	0 '	1	0	l Counting is started in t event counte		1	1 1	N	-   -
STOP TCNT	0		1	1	0	0	1	0	1 Stop both ti accumulation event counti	and		1		
EN TCNT1	1 0	1	0!	1	0 !	0	1 1	0	l Timer interr	upt	1	1		-  -   -
DIS TCNT1	1 0	1	01	1	1	0	1	0	l Timer interr	upt	1	1	; ;	-  -

# Control Instruction

D7   D6   D5   D4   D3   D2   D1   D0		<u>C</u>	A(
DIS I	1	-	-
SEL RB0   1   1   0   0   1			
SEL RB1       1   1   0   1   0   1   0   1   (BS)< 1	1	-	-
SEL MBO     1   1   1   0   0   1   0   1   (DBF) < 0	1 1	\-	-
SEL MB1   1   1   1   0   1   0   1   (DBF) < 1	1	<b>-</b> 1	-
	1 1	1	-
ENTO CIK 0 1 1 1 1 0 1 0 1 TO is enabled to 1	1		< 1 -
	1	-	N-
Old Coutput			
NOP   0 0 0 0 0 0 0 0 No operation   1	1	\ <u>-</u> "	-

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# INTEGRATED CIRCUIT TOSHIBA TECHNICAL DATA

NY.Co	1/8039PI: INDUSTRIAL SPECIFICATION  MAXIMUM RATTINGS	
SYMBOL	ITEM	RATTING
VDD	VDD Supply Voltage (with respect to GND (VSS))	[-0.5V  to  + 7V]
VCC	VCC Supply Voltage (with respect to GND (VSS))	-0.5V to + 7V
VINA	Input Voltage (Except EA)	-0.5V to + $7V$
VINB	Input Voltage (Only EA)	-0.5V to + 13V
PD	Power Dissipation (Ta = 70°C)	1.5w
TSOLDER -		260°C
TSTG	Storage Temperature	-55°C to 150°C
TOPR	Operating Temperature	1-40°C to 85°C

#### DC CHARACTERISTICS

SYMBOL	PARAMETER	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
VIL	Input Low Voltage   (Except XTAL1, XTAL2, RESET)	1 1 100 X.C	1-0.5	L.	0.7	V
VILI	Input Low Voltage  (XTAL1,XTAL2,RESET)	W.1007.	1-0.5	I.T.V	0.6	V
VIH	Input High Voltage  (Except XTAL1,XTAL2,RESET)	W W 100Y	2.2	V.J	VCC	V
VIHI	Input High Voltage (XTAL1, XTAL2, RESET)	W 100	3.8	DM.	VCC	V
VOL	Output Low Voltage (BUS)	IOL = 1.6  mA	-	-	0.45	V
VOL 1	Output Low Voltage (RD, WR, PSEN, ALE)	IOL = 1.6 mA	NY.C	Oz.	0.45	V
VOL 2	Output Low Voltage (PROG)	IOL = 0.8 mA	-71	C40	0.45	V
VOL 3	Output Low Voltage (For other output pins)	IOL = 1.2 mA	00-2	-00	0.45	V
VOH	Output High Voltage (BUS)	IOH =-280µA	2.4	-		V
VOH1	Output High Voltage (RD, WR, PSEN, ALE)	IOH =-80μA	2.4	Y.C		V
VOH 2	Output High Voltage	IOH =-30µA	2.4	07.	1-0	V
ILI	Input Leak Current (T1, INT)	VSS ≤ VIN ≤ VCC	W.	(00)	±10	   µA
ILII	Input Leak Current (P10-17, P20-P27, EA, SS)	VSS+0.45 VIN VCC	-	-	-700	μА
ILO	Output Leak Current (BUS, TO) (High impedance condition)	VSS+0.45≦VIN≦VCC !	-	_	±10	μА
IDD	VDD Supply Current				50	mΑ
IDD+ICC	Total Supply Current		_	-	170	mA

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AC CHARACTERISTICS

TA=-40°C to 85°C, VCC=VDD=+5V±10%, VSS=0V, Unless Otherwise Noted.

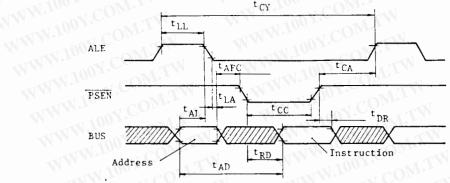
SYMBOL	PARAMETER	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
t LL	ALE Pulse Width	Win TIM	200	-	1 2 1	ns
t AL	Address Setup Time (ALE)	CON	120		4.TXN	ns
t LA	Address Hold time (ALE)	101. TIL	80		MT.	ns
t CC	Control Pulse Width(PSEN,RD,WR)	100 Y.COTT	400	-	W	ns
t DW	Data Setup Time (WR)	100X.CO	1 420	-	-W	ns
t W D	  Data Hold Time (WR)	100X.CO	80		- 1	ns
t CY	Cycle Time	M. COR	2.5	1-	15.0	μs
tDR	Data Hold Time (PSEN, RD)	CL = 20 pF	0	Q <del>\</del>	200	ns
t RD	Data Input Read Time (PSEN, RD)	MAIN	-	CTN.	400	ns
t AW	Address Setup Time (WR)	MANN TO V.C	230	σV	- }	ns
t AD	Address Setup Time (Data Input)	100	1	100 A	600	ns
tAFC	  Address Float Time (RD, PSEN)	MW 100X	-40		 	ns
t CA	Internal between Control Pulse and ALE	WW.100	10 	.M	1	ns
t CP	Port Control Setup Time (PROG)	11/1/	i 115			ns
tPC	Port Control Hold Time (PROG)		65	() In	-	ns
tPR	Port 2 Input Data Set Time  (PROG)	WW.10	007	- -01	860	ns
t DP	Output Data Setup Time (PROG)		230		-1	ns
tPD	Output Data Hold Time (PROG)	· Mari	25	-	N -	ns
tPF	Port 2 Input Data Hold Time  (PROG)	TN W	100	1 C	160	ns
tPP	PROG Pulse Width		920	) ) <del>,</del> ,	T-7/	ns
tPL	Port 2 I/O Data Setup Time	d and	300	- <b>3</b> 7	UOD)	ns
t LP	Port 2 I/O Data Hold Time		120	Mr. E.	-	ns

Note :tCY=2.5µs, Control Output:CL=80pF, BUS Output: CL=150pF, PORT20-23: CL=80pF.

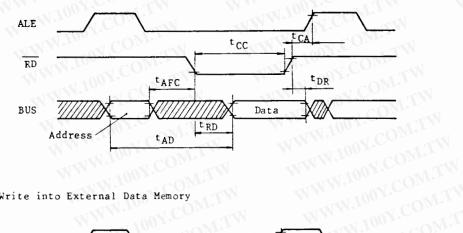
**— 758 —** 

### TIMING WAVEFORM

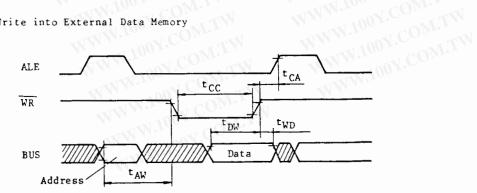
A. Instruction Fetch from External Program Memory



B. Read from External Data Memory



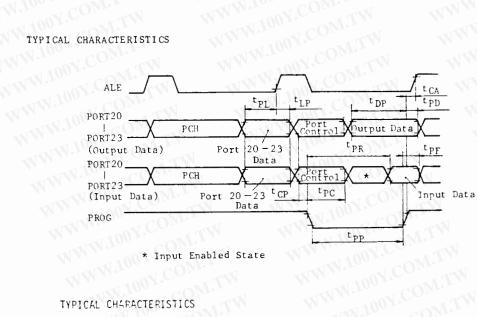
C. Write into External Data Memory



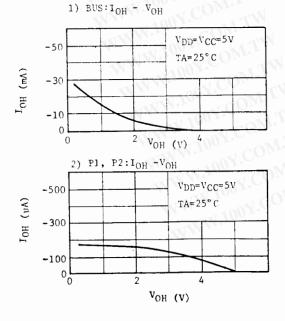
# INTEGRATED CIRCUIT TECHNICAL DATA

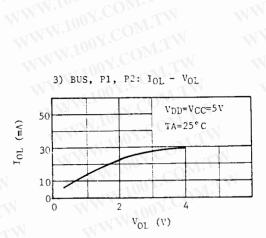
### D. Timing of Port 2 during Expander Instruction Execution

## TYPICAL CHARACTERISTICS



## TYPICAL CHARACTERISTICS

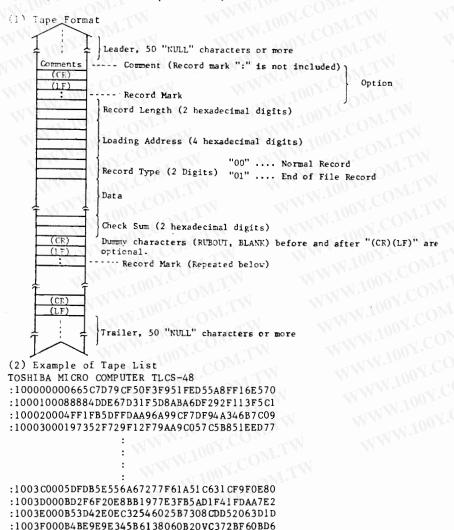




#### PROGRAM TAPE FORMAT

:0000001FF

TMP8049 programs are delivered in the form of paper tape with the following format and it is required to attach the tape list. The format of paper tape is same as the Intel type object tape (hexadecimal tape output by Intel MDS system, PROMPT 48 Development Tool, etc.)

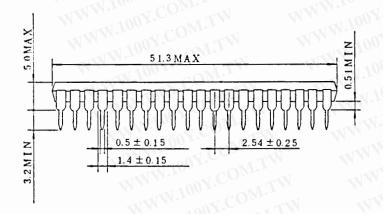


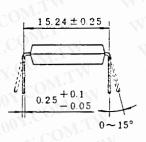
OUTLINE DRAWING

Unit in mm



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Note: 1. This dimension is measured at the center of bending point of leads.

2. Each lead pitch is 2.54mm, and all the leads are located within

±0.25mm from their theoritical positions with respect to No.1 and
No.40 leads.